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PATENT APPLICATION

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of

Docket No: Q61744

Hisayuki MIKI, et al.

Appln. No.: 09/900,962

Group Art Unit: 2812

Confirmation No.: 7972

Examiner: NOT YET ASSIGNED

Filed: July 10, 2001

For: METHOD FOR PRODUCING P-TYPE GALLIUM NITRIDE-BASED COMPOUND

SEMICONDUCTOR, METHOD FOR PRODUCING GALLIUM NITRIDE-BASED COMPOUND SEMICONDUCTOR LIGHT-EMITTING DEVICE, AND GALLIUM

NITRIDE-BASED COMPOUND SEMICONDUCTOR LIGHT-EMITTING DEVICE

RESPONSE TO RESTRICTION REQUIREMENT

Commissioner for Patents Washington, D.C. 20231

Sir:

In response to the Restriction Requirement dated September 18, 2002, Applicants elect group I claims 1-13 (drawn to a method) for prosecution, without traverse.

Respectfully submitted,

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Date: October 3, 2002

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